Sheet 1 of 1 sheet(s)

U.S. Department of Commerce, Patent and Trademark Office					Docket No.		Serial No.		
(PTO Form 1449 modified)					8327/ETCH/SILICON		10/690,318		
INFORMATION DISCLOSURE STATEMENT BY APPEICANT						Applicant		Confirmation	
DEC 1 7 2003 Hui, et al. No.:									
(Use several sheets if necessary)					Filing Date		Group		
(Use several sheets if necessary)  Examiner									
U.S. Patent Documents									
*Examiner Initial		Document Number	Issue Date	Applicant(s) Name	Class	Subclass	Filing Date If Appropriate		
EC	A1	2002/0171828	11/21/2002	Cohen et al.	356	328	07/01/2002		
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Foreign Patent Documents									
*Examiner		Document	Date	Country	Class	Subclass	Translation		
Initial		Number	_				YES	NO	
EC	B1	03/003447	01/09/2003	WIPO	H01L	21/66	$\boxtimes$		
	B2								
OTHER ART									
*Examiner Initial		Including Author, Title, Date, Pertinent Pages, Etc.							
	C1								
EC		Characterization and Metrology for UCSI Technology: 1998 International Conference, Seiler, et al., eds., pg 331-335							
	C2	Raymond, "Angle-resolved scatterometry for semiconductor manufacture,", Microlithography World, Winter 2000.							
	C3	Toprac, A., "AMD's Advanced Process Control of Ply-Gate Critical Dimension," Proc. SPIE Vol 3882, pg 62-65, Sept, 1999.							
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Examiner	Cie Chur					Date Considered 6/20/05			
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.									